



LM224A - LM324A

Low Power Quad Operational Amplifiers

- Wide gain bandwidth: 1.3MHz
- Large voltage gain: 100dB
- Very low supply current/ampli: 375 μ A
- Low input bias current: 20nA
- Low input offset voltage: 3mV max.
- Low input offset current: 2nA
- Wide power supply range:
Single supply: +3V to +30V
Dual supplies: ± 1.5 V to ± 15 V
- Input common-mode voltage range includes ground
- ESD internal protection: 2KV

Description

These circuits consist of four independent, high gain, internally frequency compensated operational amplifiers. They operate from a single power supply over a wide range of voltages.

Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage.

All the pins are protected against electrostatic discharges up to 2KV (as a consequence, the input voltages must not exceed the magnitude of V_{CC}^+ or V_{CC}^- .)

Order Codes

Part Number	Temperature Range	Package	Packaging
LM224AN	-40°C, +105°C	DIP	Tube
LM224AD/ADT		SO	Tube or Tape & Reel
LM224APT		TSSOP (Thin Shrink Outline Package)	Tape & Reel
LM324AN	0°C, +70°C	DIP	Tube
LM324AD/ADT		SO	Tube or Tape & Reel
LM324APT		TSSOP (Thin Shrink Outline Package)	Tape & Reel


N
DIP14
(Plastic Package)


D
SO-14
(Plastic Micropackage)


P
TSSOP-14
(Thin Shrink Small Outline Package)

1 Pin & Schematic Diagram

Figure 1: Pin connections (top view)

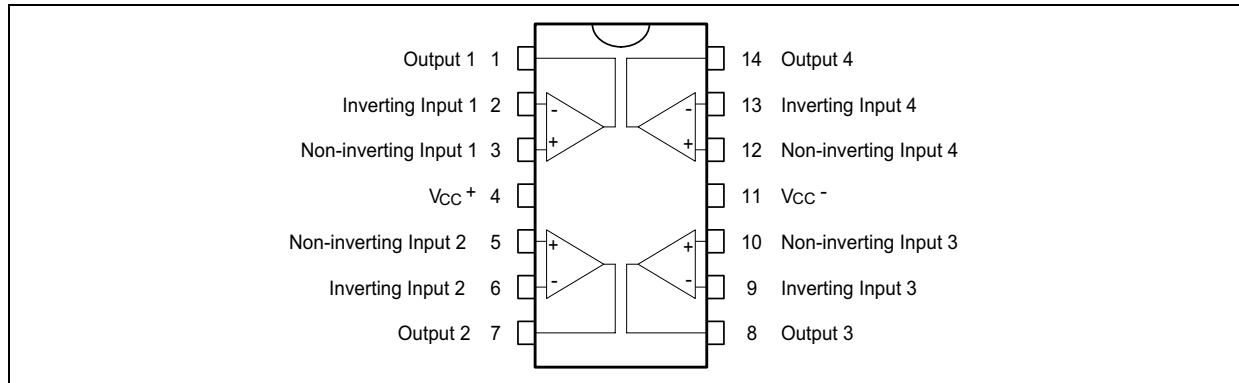
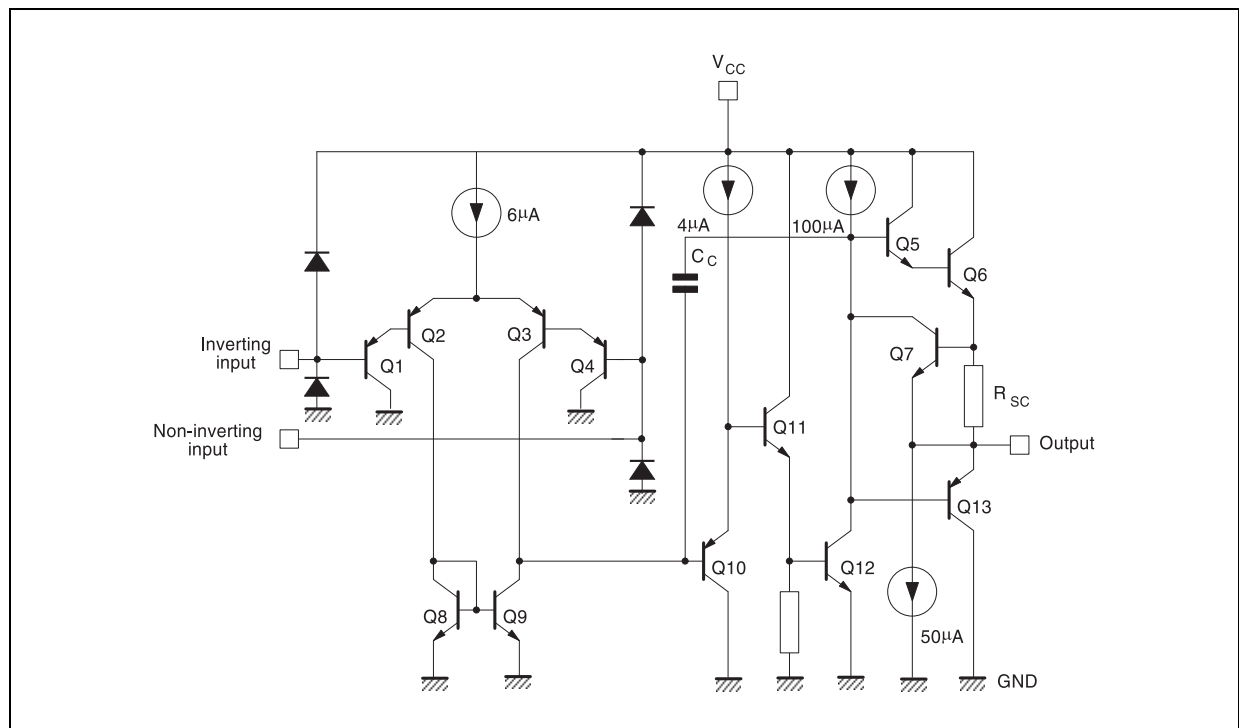


Figure 2: Schematic diagram (1/4 LM124A)



2 Absolute Maximum Ratings

Table 1: Key parameters and their absolute maximum ratings

Symbol	Parameter	LM124A	LM224A	LM324A	Unit
V _{CC}	Supply voltage	±16 or 32			V
V _i	Input Voltage	-0.3 to V _{CC} + 0.3			V
V _{id}	Differential Input Voltage ¹	32			V
P _{tot}	Power DissipationN Suffix D Suffix	500	500 400	500 400	mW mW
	Output Short-circuit Duration ²	Infinite			
I _{in}	Input Current ³	50			mA
T _{oper}	Operating Free-air Temperature Range	-55 to +125	-40 to +105	0 to +70	°C
T _{stg}	Storage Temperature Range	-65 to +150			°C
R _{thja}	Thermal Resistance Junction to Ambient SO14 TSSOP14 DIP14	103 100 66			°C/W

1) Either or both input voltages must not exceed the magnitude of V_{CC}⁺ or V_{CC}⁻.

2) Short-circuits from the output to V_{CC} can cause excessive heating if V_{CC} > 15V. The maximum output current is approximately 40mA independent of the magnitude of V_{CC}. Destructive dissipation can result from simultaneous short-circuit on all amplifiers.

3) This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward biased and thereby acting as input diodes clamps. In addition to this diode action, there is also NPN parasitic action on the IC chip. this transistor action can cause the output voltages of the op-amps to go to the V_{CC} voltage level (or to ground for a large overdrive) for the time duration than an input is driven negative. This is not destructive and normal output will set up again for input voltage higher than -0.3V.

3 Electrical Characteristics

Table 2: $V_{CC}^+ = +5V$, $V_{CC}^- = \text{Ground}$, $V_o = 1.4V$, $T_{amb} = +25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V_{io}	Input Offset Voltage - note ¹ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		2	3 5	mV
I_{io}	Input Offset Current $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		2	20 40	nA
I_{ib}	Input Bias Current - note ² $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	100 200	nA
A_{vd}	Large Signal Voltage Gain $V_{CC}^+ = +15V$, $R_L = 2k\Omega$, $V_o = 1.4V$ to $11.4V$ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	50 25	100		V/mV
SVR	Supply Voltage Rejection Ratio ($R_s \leq 10k\Omega$) $V_{CC}^+ = 5V$ to $30V$ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	65 65	110		dB
I_{CC}	Supply Current, all Amp, no load $T_{amb} = +25^\circ C$ $V_{CC} = +5V$ $V_{CC} = +30V$ $T_{min} \leq T_{amb} \leq T_{max}$ $V_{CC} = +5V$ $V_{CC} = +30V$		0.7 1.5 0.8 1.5	1.2 3 1.2 3	mA
V_{icm}	Input Common Mode Voltage Range $V_{CC} = +30V$ - note ³ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	0 0		$V_{CC} - 1.5$ $V_{CC} - 2$	V
CMR	Common Mode Rejection Ratio ($R_s \leq 10k\Omega$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	70 60	80		dB
I_{source}	Output Current Source ($V_{id} = +1V$) $V_{CC} = +15V$, $V_o = +2V$	20	40	70	mA
I_{sink}	Output Sink Current ($V_{id} = -1V$) $V_{CC} = +15V$, $V_o = +2V$ $V_{CC} = +15V$, $V_o = +0.2V$	10 12	20 50		mA μA
V_{OH}	High Level Output Voltage $V_{CC} = +30V$ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$ $V_{CC} = +5V$, $R_L = 2k\Omega$ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$	26 26 27 27 3.5 3	27 28		V

Table 2: $V_{CC}^+ = +5V$, $V_{CC}^- = \text{Ground}$, $V_o = 1.4V$, $T_{amb} = +25^\circ C$ (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
VOL	Low Level Output Voltage ($R_L = 10k\Omega$) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		5	20 20	mV
SR	Slew Rate $V_{CC} = 15V$, $V_i = 0.5$ to $3V$, $R_L = 2k\Omega$, $C_L = 100pF$, unity Gain		0.4		V/ μs
GBP	Gain Bandwidth Product $V_{CC} = 30V$, $f = 100kHz$, $V_{in} = 10mV$, $R_L = 2k\Omega$, $C_L = 100pF$		1.3		MHz
THD	Total Harmonic Distortion $f = 1kHz$, $A_v = 20dB$, $R_L = 2k\Omega$, $V_o = 2V_{pp}$, $C_L = 100pF$, $V_{CC} = 30V$		0.015		%
e_n	Equivalent Input Noise Voltage $f = 1kHz$, $R_s = 100\Omega$, $V_{CC} = 30V$		40		$\frac{nV}{\sqrt{Hz}}$
DV_{io}	Input Offset Voltage Drift		7	30	$\mu V/^\circ C$
DI_{io}	Input Offset Current Drift		10	200	$pA/^\circ C$
V_{o1}/V_{o2}	Channel Separation - note ⁴ $1kHz \leq f \leq 20kHz$		120		dB

1) $V_o = 1.4V$, $R_s = 0\Omega$, $5V < V_{CC}^+ < 30V$, $0 < V_{ic} < V_{CC}^+ - 1.5V$

2) The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.

3) The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than $0.3V$. The upper end of the common-mode voltage range is $V_{CC}^+ - 1.5V$, but either or both inputs can go to $+32V$ without damage.

4) Due to the proximity of external components insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of capacitance increases at higher frequencies.

Figure 3: Input bias current vs. ambient temperature

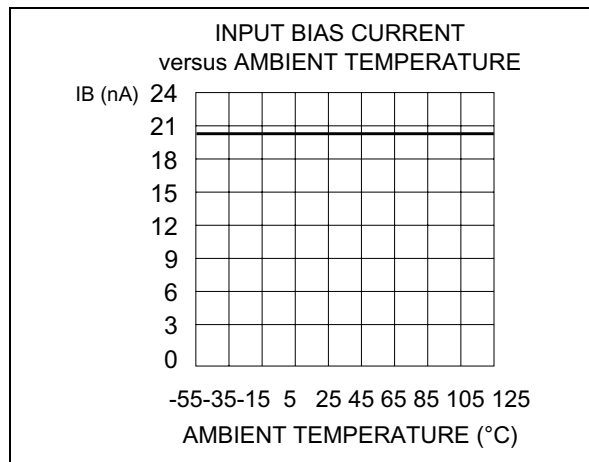


Figure 4: Input voltage range

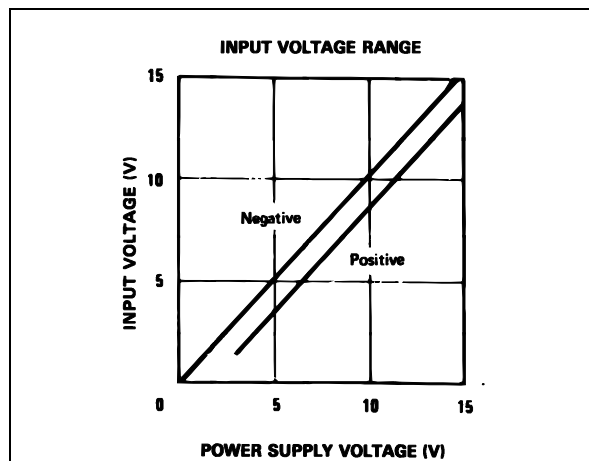


Figure 5: Gain bandwidth product

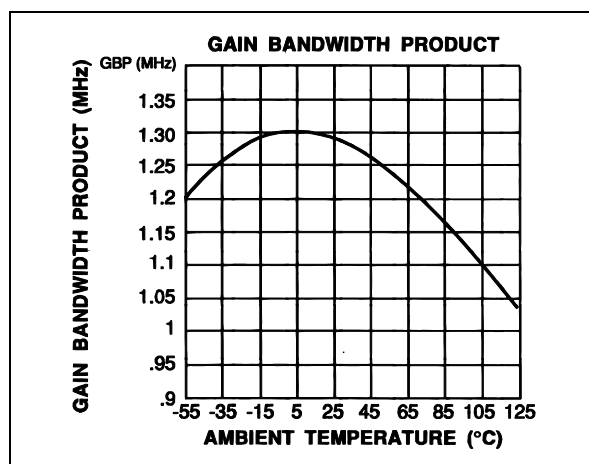


Figure 6: Current limiting

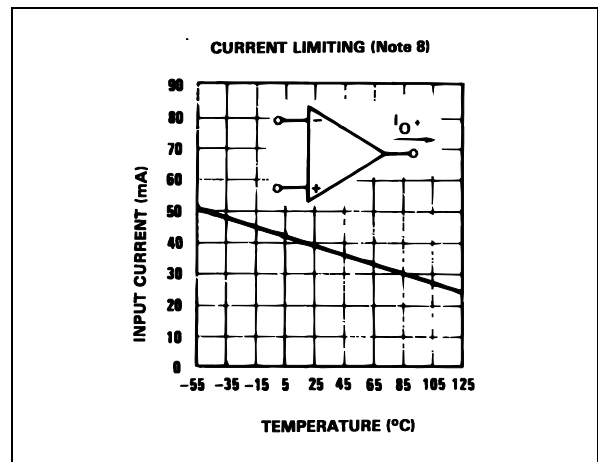


Figure 7: Supply current

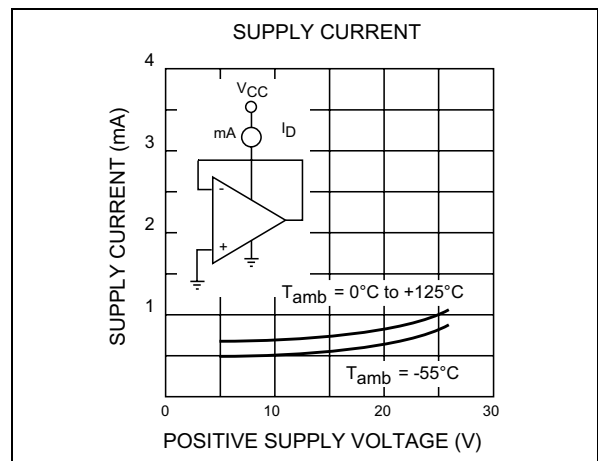


Figure 8: Common mode rejection ratio

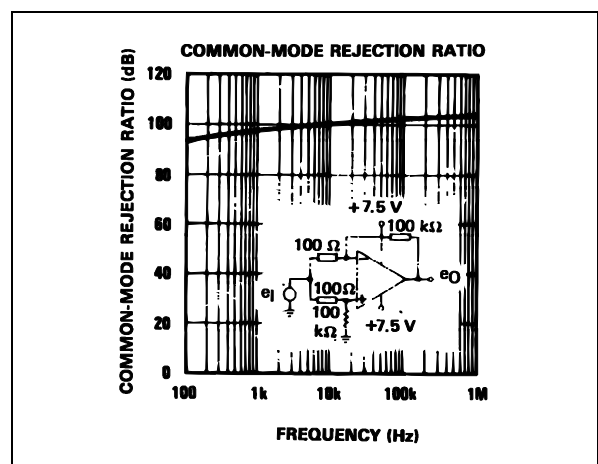


Figure 9: Electrical curves

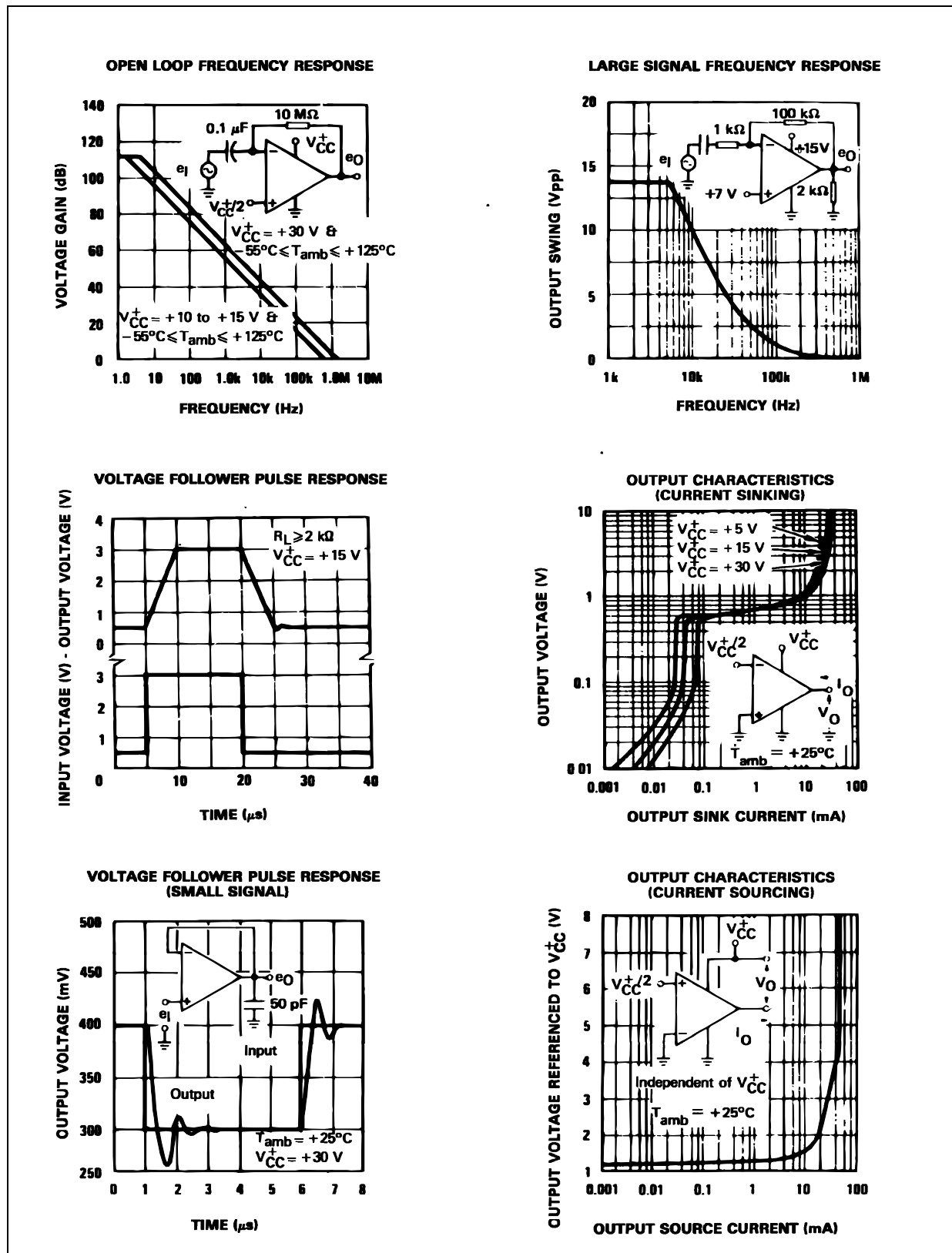


Figure 10: Input current

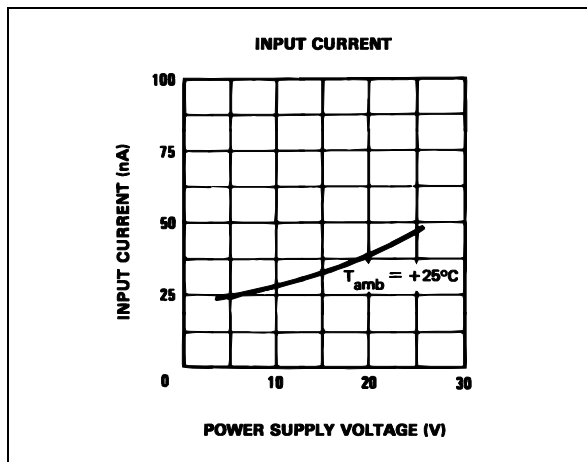


Figure 11: Power supply & common mode rejection ratio

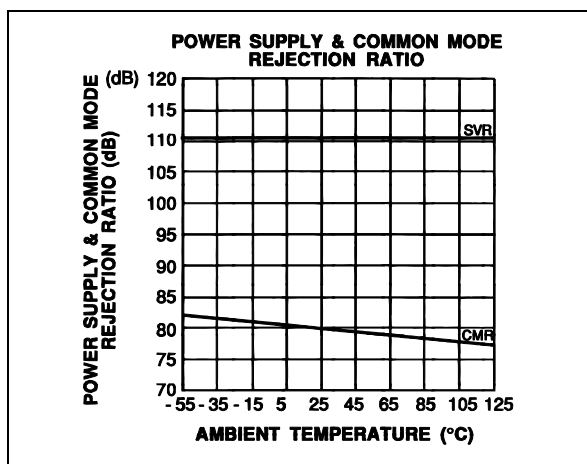


Figure 12: Voltage gain

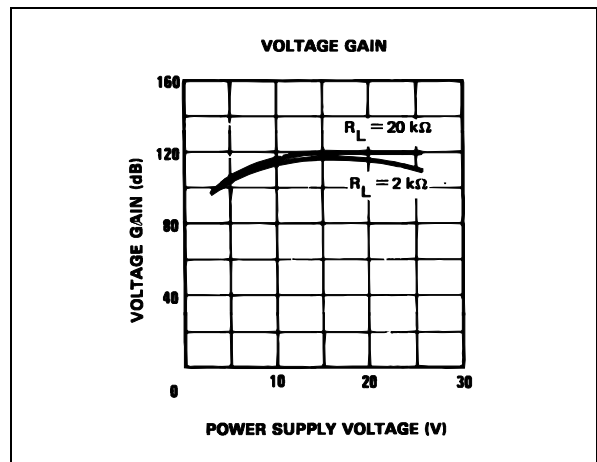
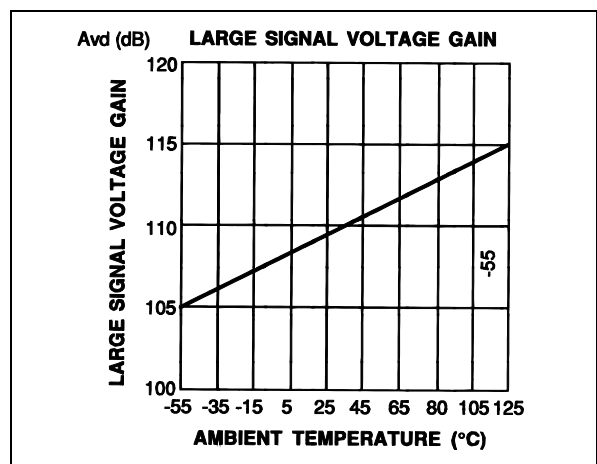


Figure 13: Large signal voltage gain



4 Typical Single - Supply Applications

Figure 14: AC coupled interting amplifier

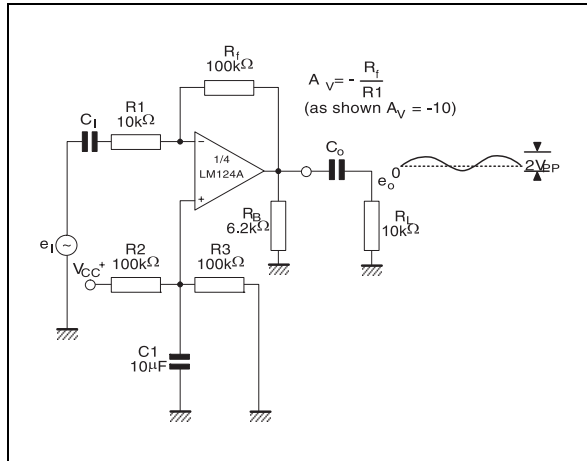


Figure 15: AC coupled non inverting amplifier

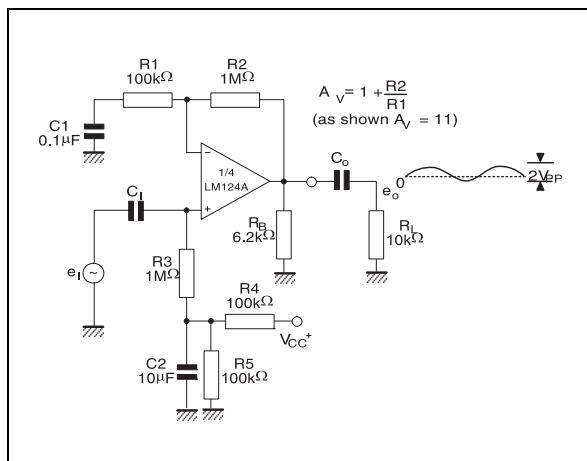


Figure 16: Non-inverting DC gain

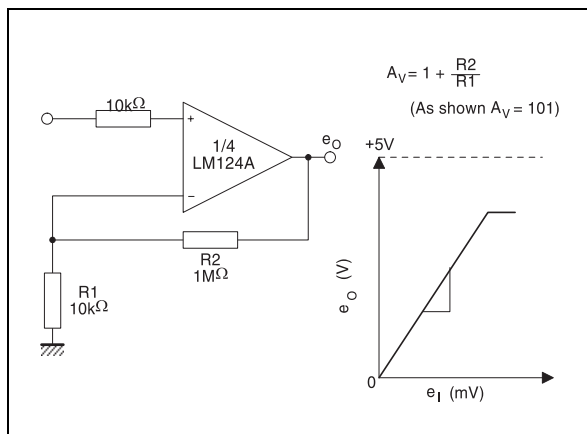


Figure 17: High input Z adjustable gain DC instrumentation amplifier

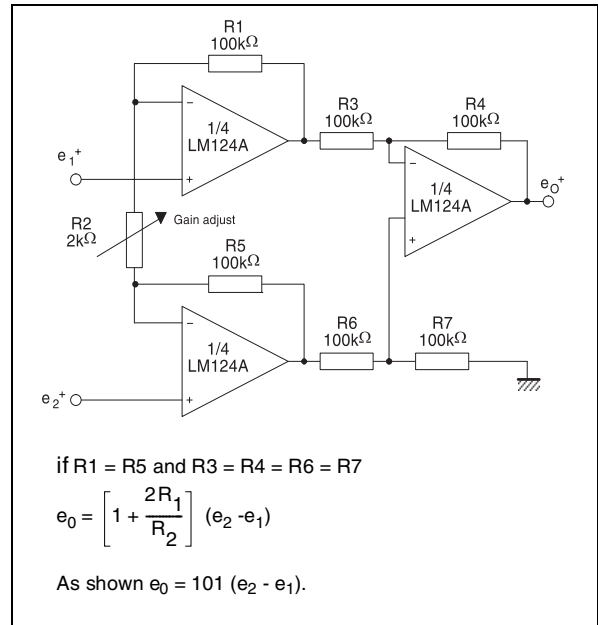


Figure 18: DC summing amplifier

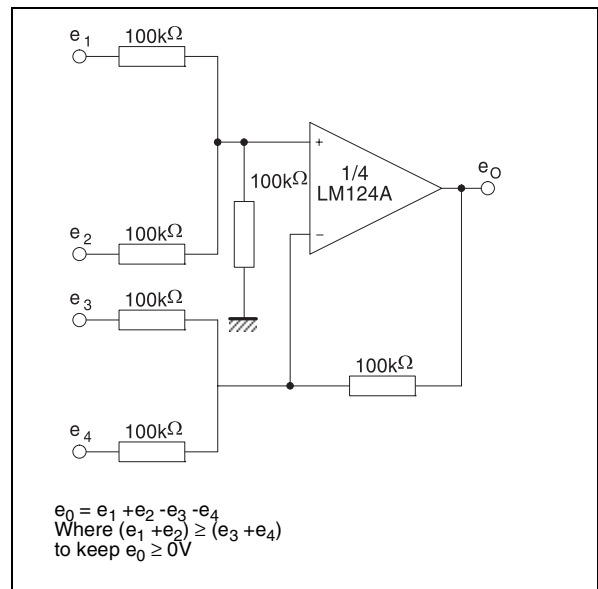


Figure 19: Low drift peak detector

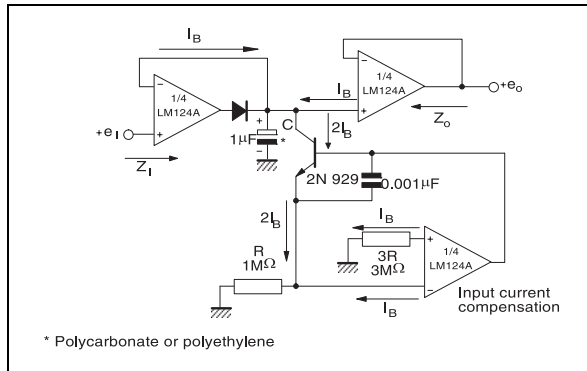


Figure 20: Activer bandpass filter

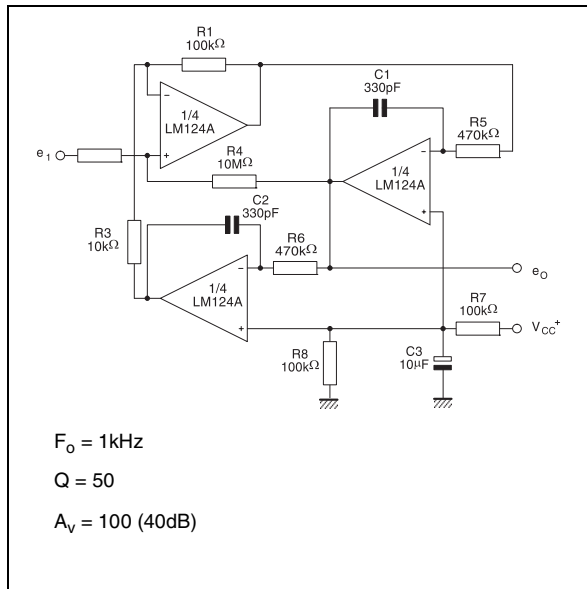
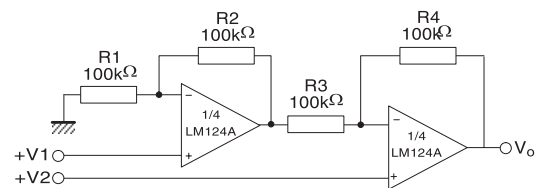


Figure 21: High input Z, DC differential amplifier

$$\text{For } \frac{R_1}{R_2} = \frac{R_4}{R_3}$$

(CMRR depends on this resistor ratio match)



$$e_o \left(1 + \frac{R_4}{R_3} \right) (e_2 - e_1)$$

As shown $e_o = (e_2 - e_1)$

Figure 22: Using symmetrical amplifiers to reduce input current (general concept)

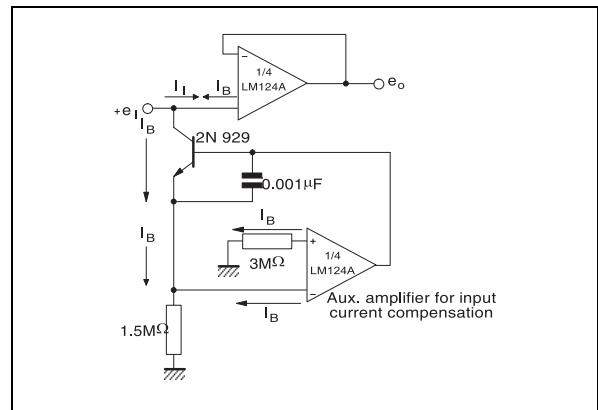


Table 3: $V_{CC}^{+} = +15V$, $V_{CC}^{-} = 0V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

Symbol	Conditions	Value	Unit
V_{io}		0	mV
A_{vd}	$R_L = 2k\Omega$	100	V/mV
I_{cc}	No load, per amplifier	350	μA
V_{icm}		0 to +13.5	V
V_{OH}	$R_L = 2k\Omega$ ($V_{CC}^{+}=15V$)	+13.5	V
V_{OL}	$R_L = 10k\Omega$	5	mV
I_{os}	$V_o = +2V$, $V_{CC} = +15V$	+40	mA
GBP	$R_L = 2k\Omega$, $C_L = 100pF$	1.3	MHz
SR	$R_L = 2k\Omega$, $C_L = 100pF$	0.4	V/ μs

5 Macromodel



Warning: *Please consider following remarks before using this macromodel:*

All models are a trade-off between accuracy and complexity (i.e. simulation time).

Macromodels are not a substitute to breadboarding; rather, they confirm the validity of a design approach and help to select surrounding component values.

A macromodel emulates the NOMINAL performance of a TYPICAL device within SPECIFIED OPERATING CONDITIONS (i.e. temperature, supply voltage, etc.). Thus the macromodel is often not as exhaustive as the datasheet, its goal is to illustrate the main parameters of the product.

Data issued from macromodels used outside of its specified conditions (Vcc, Temperature, etc) or even worse: outside of the device operating conditions (Vcc, Vicm, etc) are not reliable in any way.

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** Standard Linear Ics Macromodels, 1993.
** CONNECTIONS :
* 1 INVERTING INPUT
* 2 NON-INVERTING INPUT
* 3 OUTPUT
* 4 POSITIVE POWER SUPPLY
* 5 NEGATIVE POWER SUPPLY
.SUBCKT LM324 1 2 3 4 5
*****
.MODEL MDTH D IS=1E-8 KF=3.104131E-15 CJO=10F
* INPUT STAGE
CIP 2 5 1.000000E-12
CIN 1 5 1.000000E-12
EIP 10 5 2 5 1
EIN 16 5 1 5 1
RIP 10 11 2.600000E+01
RIN 15 16 2.600000E+01
RIS 11 15 2.003862E+02
DIP 11 12 MDTH 400E-12
DIN 15 14 MDTH 400E-12
VOFP 12 13 DC 0
VOFN 13 14 DC 0
IPOL 13 5 1.000000E-05
CPS 11 15 3.783376E-09
DINN 17 13 MDTH 400E-12
VIN 17 5 0.000000E+00
DINR 15 18 MDTH 400E-12
VIP 4 18 2.000000E+00
FCP 4 5 VOFP 3.400000E+01
FCN 5 4 VOFN 3.400000E+01
FIBP 2 5 VOFN 2.000000E-03
FIEN 5 1 VOFP 2.000000E-03
* AMPLIFYING STAGE
FIP 5 19 VOFP 3.600000E+02
FIN 5 19 VOFN 3.600000E+02
RG1 19 5 3.652997E+06
RG2 19 4 3.652997E+06
CC 19 5 6.000000E-09
DOPM 19 22 MDTH 400E-12
DONM 21 19 MDTH 400E-12
HOPM 22 28 VOUT 7.500000E+03
VIPM 28 4 1.500000E+02
HONM 21 27 VOUT 7.500000E+03
VINM 5 27 1.500000E+02
EOUT 26 23 19 5 1
VOUT 23 5 0
ROUT 26 3 20
COUT 3 5 1.000000E-12
DOP 19 25 MDTH 400E-12
VOP 4 25 2.242230E+00
DON 24 19 MDTH 400E-12
VON 24 5 7.922301E-01
ENDS

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6 Package Mechanical Data

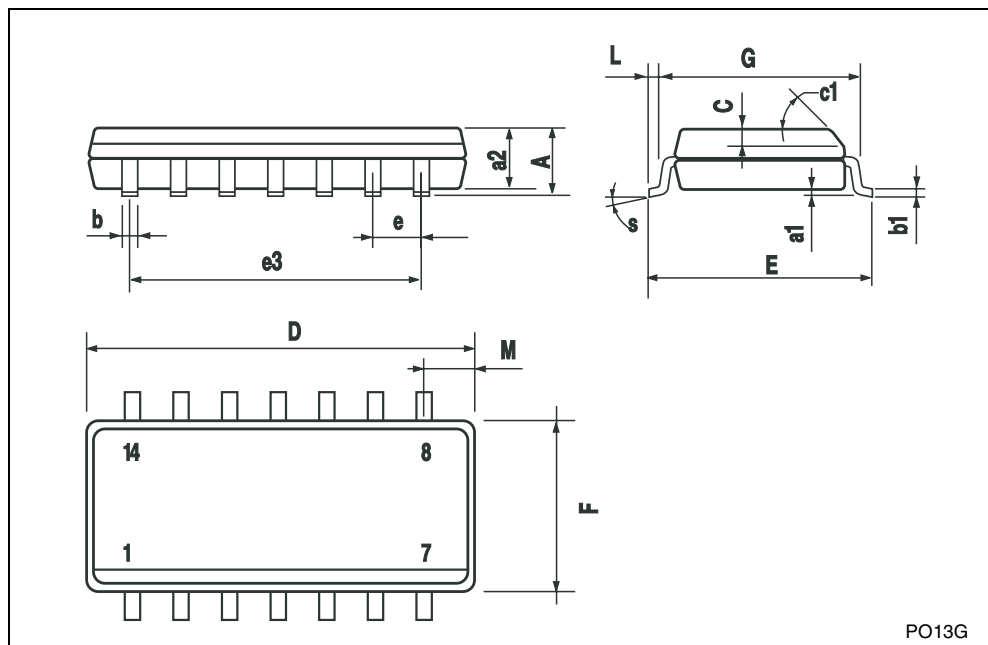
6.1 DIP14 Package

Plastic DIP-14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
I			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

P001A

6.2 SO-14 Package

SO-14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.068
a1	0.1		0.2	0.003		0.007
a2			1.65			0.064
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.019	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.344
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
M			0.68			0.026
S	8° (max.)					



6.3 TSSOP14 Package

TSSOP14 MECHANICAL DATA						
DIM.	mm.			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.0089
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
e		0.65 BSC			0.0256 BSC	
K	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030

0080337D

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7 Summary of Changes

Date	Revision	Description of Changes
01 March 2001	1	First Release
01 Feb. 2005	2	- Table 1 on page 3 : explanation of Vid and Vi limits - Macromodel updated